



DATASHEET
FEUILLE DE SPECIFICATIONS

P/N: AAMCS-AMP-8G-11G-50dB-50dBm-0-C
Designation: 100W, 50dB, 8-11GHz Amplifier Module



8 – 11 GHz 100W Power Amplifier Module

Ed.	Written by	Date	Observation	Approved by
0	A. Billy	09/11/2016	Création (ET16015)	



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Electrical features <i>Caractéristiques électriques</i>		All parameters specified @ baseplate temperature of +25°C and supply of 28Vdc, unless otherwise specified	
Electrical parameters <i>Paramètres électriques</i>	Measuring conditions <i>Conditions de mesure</i>	AA-MCS specifications <i>Spécifications AA-MCS</i>	Units <i>Unités</i>
Bandwidth <i>Bande de fréquence</i>		8 – 11	GHz
Output power – PW mode <i>Puissance de sortie – Mode pulsé</i>	@ Psat – pulsed (PW) Pulse duration: 100µs max. Duty cycle (DC): 10% max.	49 min. 50 typ.	dBm
Input power – PW mode <i>Puissance d'entrée – Mode pulsé</i>	For rated power Maximum level	0 typ. +5 max.	dBm
Output power – CW mode <i>Puissance de sortie – Mode CW</i>	CW	47 max. (user must take care not to exceed 47dBm CW)	dBm
Input power – CW mode <i>Puissance d'entrée – Mode CW</i>	For 50W output power Maximum level	-12 typ. -10 max.	dBm
Gain <i>Gain</i>	Small signal CW @ Psat – PW	55 typ. 49 min. 52 typ.	dB
In band Gain ripple <i>Ondulation de gain</i>	@ Psat – PW	+/- 1 max.	dB
Impedance <i>Impedance</i>		50	Ohms
Input / Output VSWR <i>TOS d'entrée / sortie</i>	Input Output	1.5:1 typ. 2:1 max. 1.5:1 typ. 2:1 max.	
Load mismatch <i>Résistance au TOS de charge</i>		3:1 max.	
Time for RF on/off (blinking) <i>Vitesse d'extinction RF</i>	10-90% RF rise / fall time	0.2 typ. 1 max.	µs
Power density in blanking mode <i>Densité spectrale de puissance</i>	In 2 MHz BW	-120 max. RF switch in TX path and gate bias cut-off	dBm

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Spurious <i>Parasites</i>	@ Psat	-65 max.	dBc
Operating class <i>Classe de fonctionnement</i>		AB on GaN devices	
Supply voltage <i>Tension d'alimentation</i>	"Vcc" (With output power derating if Vcc < typical value)	+25 min. +28 typ. +32 max.	Vdc
Current consumption <i>Courant consommé</i>	Blanking ON Small signal, CW @Psat, PW: 100µs, 10%	0.2 typ. 2.2 typ. 12 typ. 15 max.	A (instantaneous)
Tension de control température <i>Temperature voltage monitoring</i>	Positive slope	10 -300mV @ -30°C 0V @ 0°C +600mV @ +60°C	mV/°C

Control, Alarms and Monitoring <i>Contrôles, Alarmes et Informations</i>		
Parameters <i>Paramètres</i>	Description <i>Description</i>	Spécifications <i>Specifications</i>
Noise quieting / RF blanking control <i>Commande d'extinction RF</i>	1 solder pin TTL command "Blanking"	Low or Not Connected = RF Output ON High = RF Output OFF (Muted)
Temperature analog signal <i>Lecture temperature</i>	1 solder Pin Signal "Temperature"	Analog Refer to Electrical features

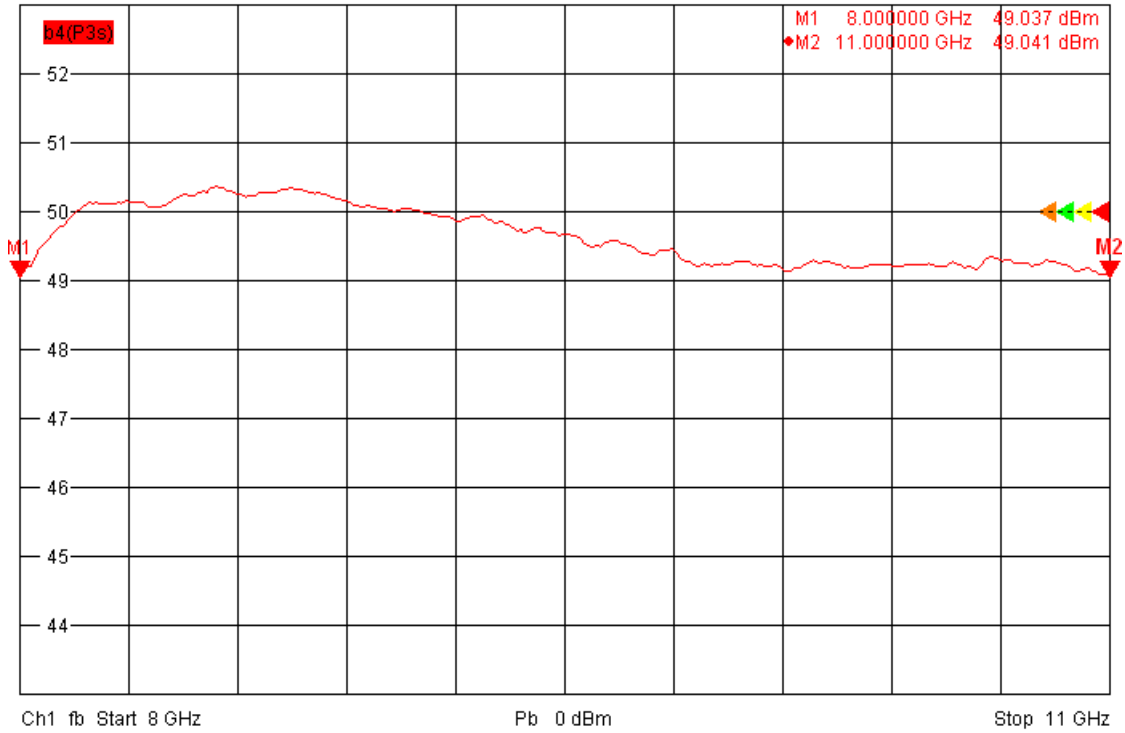
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PWR **b4(P3s)** dB Mag 1 dB / Ref 50 dBm PCai Smo 2 (Max)
 Mem1[PWR] **b4(P3s)** dB Mag 1 dB / Ref 50 dBm Invisible
 Mem2[PWR] **b4(P3s)** dB Mag 1 dB / Ref 50 dBm Smo
 Mem3[PWR] **b4(P3s)** dB Mag 1 dB / Ref 50 dBm Smo



Saturated Output power in pulsed mode @ +25°C (0dBm input power)

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Mechanical features <i>Caractéristiques mécaniques</i>			
Parameters <i>Paramètres</i>	Measuring conditions <i>Conditions de mesure</i>	AA-MCS specifications <i>Spécifications AA-MCS</i>	Units <i>Unités</i>
Length x width x height <i>Longueur x largeur x Hauteur</i>	L x W x H ISO 2768-mH	110 x 65 x 24 max. (without connectors) (see drawings below)	mm
RF Connectors <i>Connectique RF</i>	Input / Output	SMA female	-
Supply & Control connectors <i>Connecteurs de contrôle et alim.</i>	Supply + GND "Blanking" & "Temperature"	Solderable feedthru and pins	
Weight <i>Masse</i>		450 max.	g
Housing <i>Châssis</i>		Aluminium coated with Nickel	
Sealing <i>Etanchéité</i>		Hermetically sealed	

Mechanical interfaces:



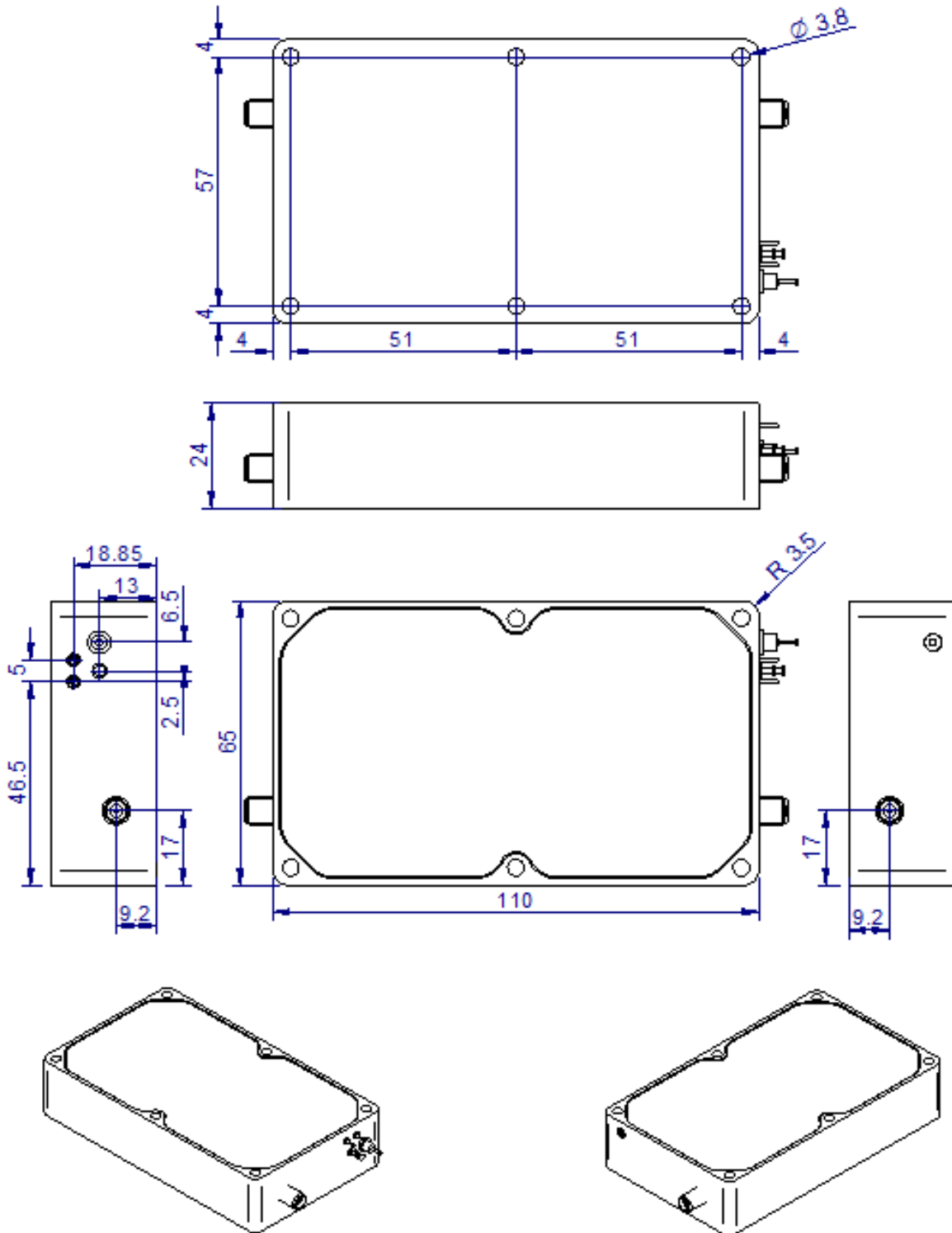
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Mechanical drawing:



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Environmental conditions
Conditions environnementales

Parameters <i>Paramètres</i>	Measuring conditions <i>Conditions de mesure</i>	AA-MCS specifications <i>Spécifications AA-MCS</i>	Units <i>Unités</i>
Cold temperature operation <i>Température de service à froid</i>	Case temperature	-32 min.	°C
Cold temperature storage <i>Température de stockage à froid</i>	Case temperature	-46 min.	°C
Dry heat temperature operation <i>Température de service à chaud</i>	Case temperature	+85 max. <i>(includes automatic shutdown with recovery when baseplate temperature exceeds +90°C)</i>	°C
Dry heat temperature storage <i>Température de stockage à chaud</i>	Case temperature	+85 max.	°C
Altitude <i>Altitude</i>		30 000 max.	ft
Sand and dust <i>Sable et poussières</i>		As per MIL-STD-810G method 510.5 procedure I & II	
Humidity <i>Humidité</i>	97% @ +26°C	As per MIL-STD-810G method 507.5 procedure II	%
Functional random vibrations <i>Vibrations aléatoires opération</i>		MIL-STD-810G method 514.5 procedure I Airborne	
Functional shocks <i>Chocs fonctionnels</i>		As per MIL-STD-810G method 516.6 procedure I 20g	
Functional acceleration <i>Accélération fonctionnelle</i>		Forward 12g Back 4g Up 4g Down 2g Lateral 3g	

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